

High Power Pulsed Laser Diodes 905D3J09-Series

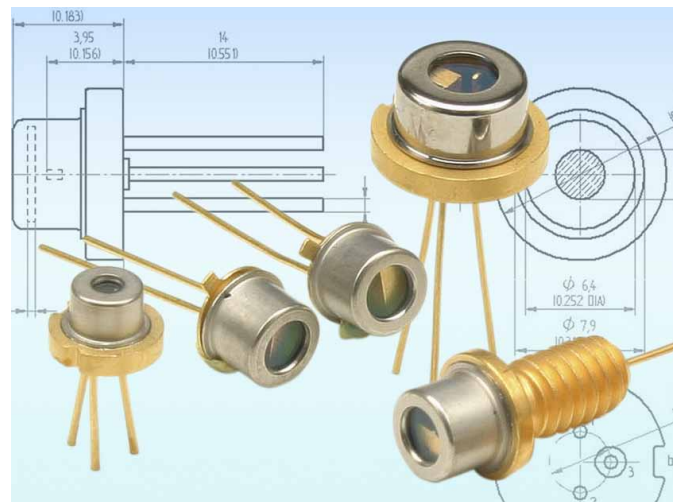


FEATURES

- Multi-Junction devices up to 200 Watts
- Proven InGaAs / GaAs high reliability structure
- High power large-optical-cavity (LOC) structure for a narrow far-field
- Excellent temperature stability
- Hermetic and custom designed package

APPLICATIONS

- Range finding
- Surveying equipment
- Weapons simulation
- Laser radar
- Ceilometer
- Optical trigger
- Medical



OPTICAL CHARACTERISTICS AT $t_{RT}= 25^{\circ}C$

	MIN	TYP	MAX	UNITS
Wavelength of peak radiant intensity λ_m	895	905	915	nm
Spectral bandwidth $\Delta\lambda$ at 50% intensity points		8		nm
Wavelength temperature coefficient		0.27		nm/ $^{\circ}C$
Beam spread (50% peak intensity)				
- Parallel to junction plane \parallel		12		Degrees
- Perpendicular to junction plane \perp		20		Degrees



OPTICAL CHARACTERISTICS AT $t_{RT}= 21^{\circ}\text{C}$, $t_w= 100\text{ ns}$, $P_{rr}= 3.33\text{ kHz}$, $I_F= 35\text{ A}$

PARAMETER	905D1S3J09X	905D2S3J09X	905D3S3J09X
Number of element	1 x 3	2 x 3	3 x 3
P_o at I_F (typ.)	75 W	135 W	200 W
Emitting area	235 x 10 μm	235 μm x 200 μm	235 μm x 400 μm
I_{th} typ.	800 mA	800 mA	800 mA

ABSOLUTE MAXIMUM RATINGS

Maximum ratings	Limiting values
Peak reverse voltage	6 V
Max. peak forward current I_{FM}	35 A
Pulse duration	
Single element	150 ns
Stacks	150 ns
Duty factor	0.1%
Temperature	
Storage	-55°C to + 100°C
Operating	-45°C to + 85°C
Lead soldering	
5 seconds max at	200°C



Figure 1:
Optical Output Power vs. Forward Current

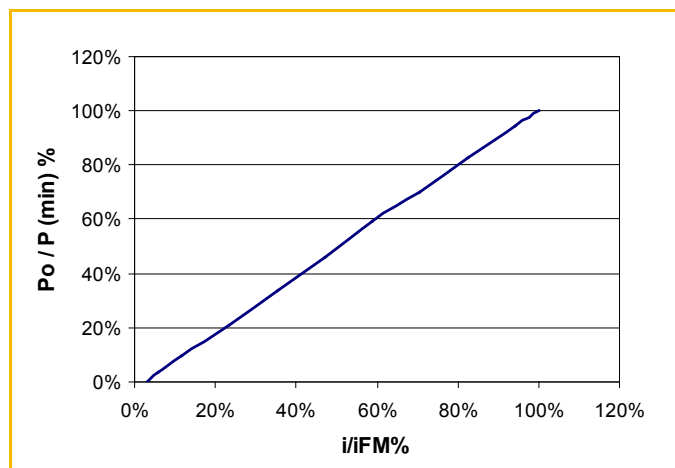


Figure 2:
Output Power vs. Temperature

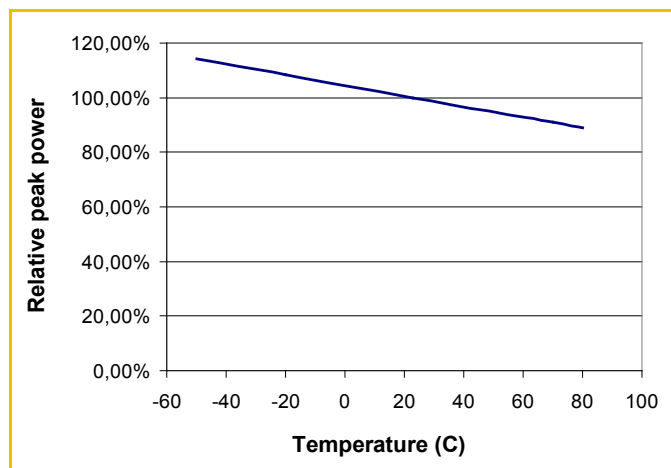


Figure 3:
Wavelength vs. Temperature

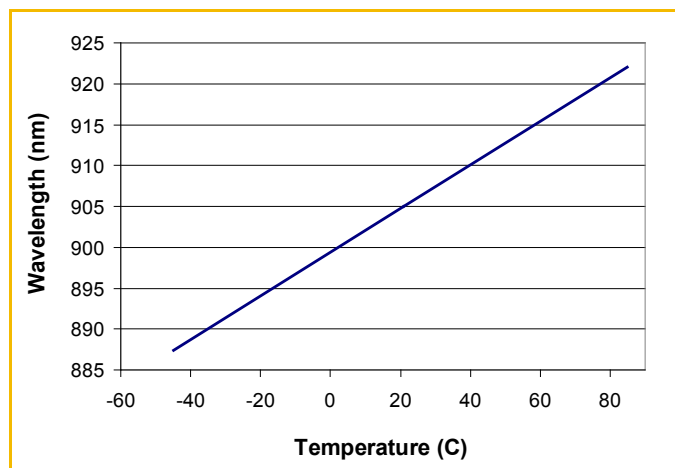


Figure 4:
Spectral Intensity Distribution

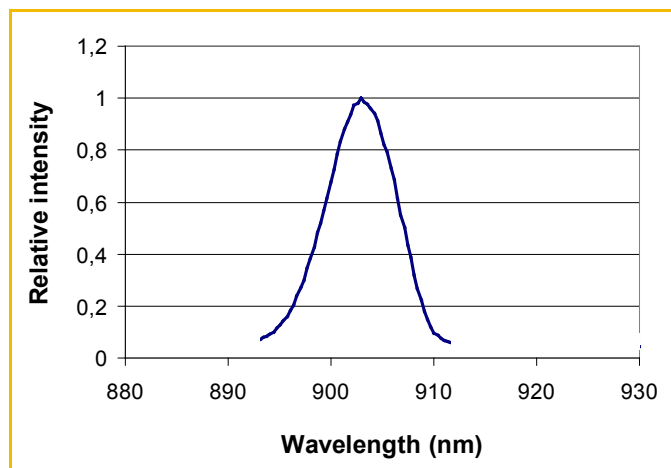
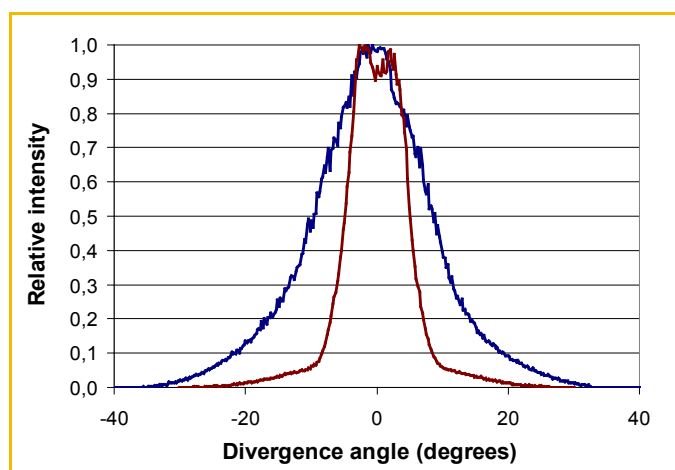


Figure 5:
Far Field Emission Parallel and Perpendicular to Junction Plane



PRODUCT NUMBER DESIGNATION



Diode Configuration

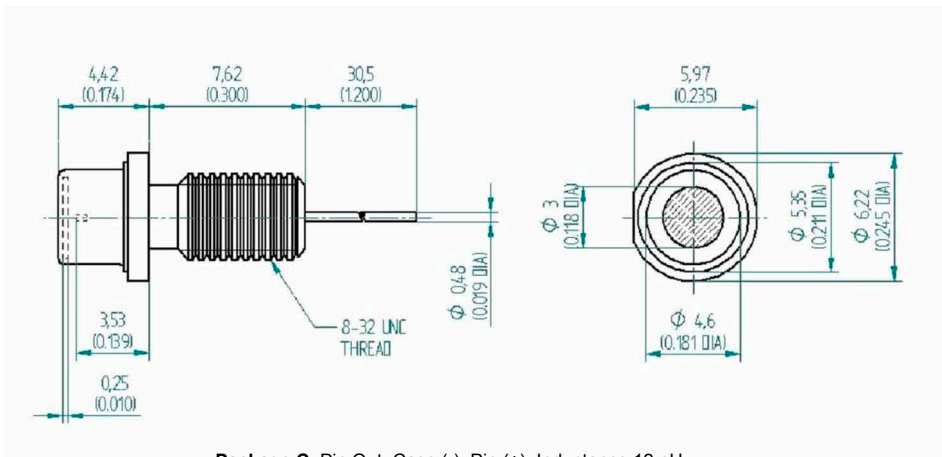
1S = single stack
2S = double stack
3S = triple stack

Package Style

C = 8 – 32 coax
R = 9 mm CD
S = TO-18
Y = ceramic

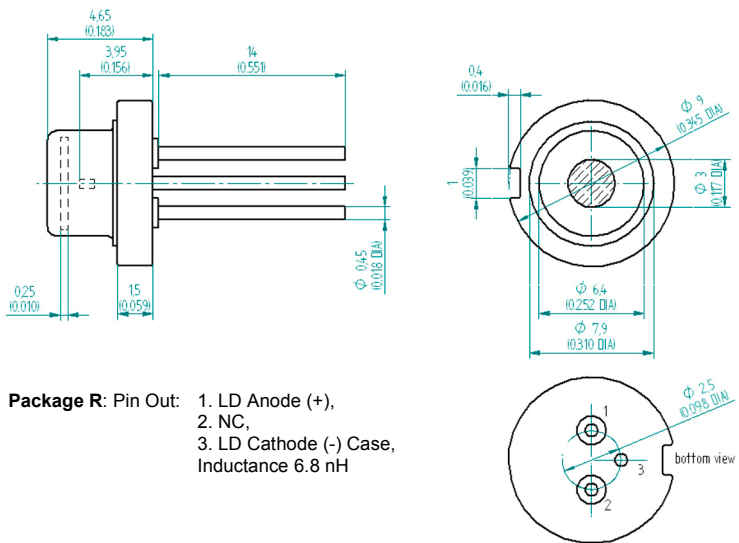
PACKAGE DRAWING

Package C 8 – 32 coax



Package C: Pin Out: Case (-), Pin (+), Inductance 12 nH

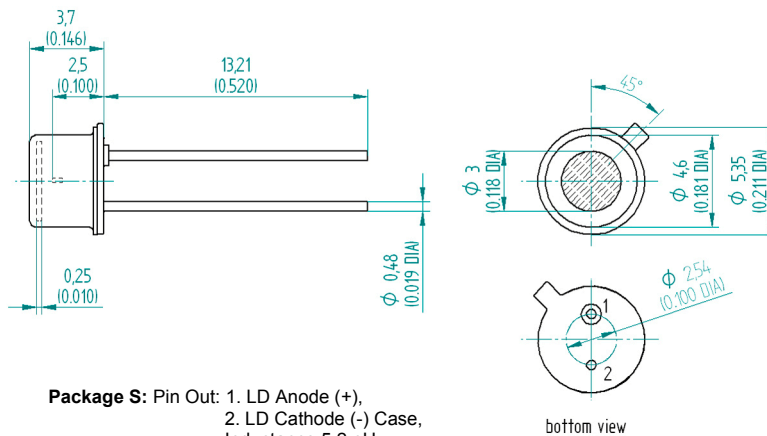
Package R 9 mm CD



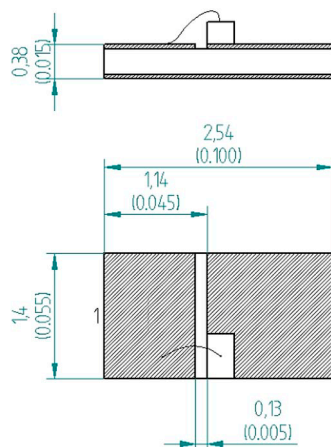
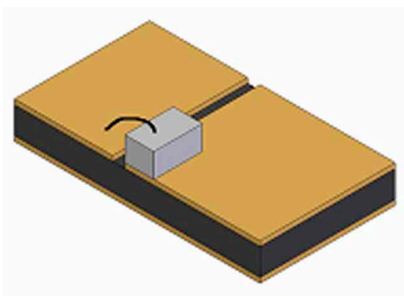
Package R: Pin Out: 1. LD Anode (+), 2. NC, 3. LD Cathode (-) Case, Inductance 6.8 nH



Package S TO-18



Package Y ceramic carrier



Package Y: Pin Out: 1. LD Anode (+), 2. LD Cathode (-), Inductance 1.6 nH



PRODUCT CHANGES

LASER COMPONENTS reserves the right to make changes to the product(s) or information contained herein without notice. No liability is assumed as a result of their use or application.

ORDERING INFORMATION

Products can be ordered directly from LASER COMPONENTS or its representatives. For a complete listing of representatives, visit our website at www.lasercomponents.com

Custom designed products are available on request.

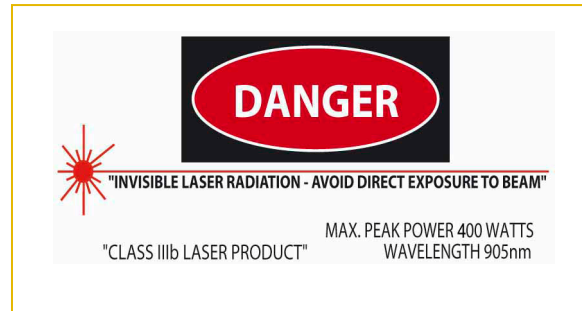
LASER SAFETY

Personal Hazard:

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 "Safety of laser products".

Handling Precautions:

Products are subject to the risks normally associated with sensitive electronic devices including static discharge, transients, and overload.



04/11 / V8 / HW / lcc/ 905d3j09.doc

